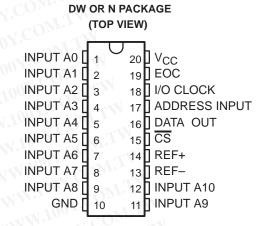
- 8-Bit Resolution A/D Converter
- Microprocessor Peripheral or Stand-Alone Operation
- On-Chip 12-Channel Analog Multiplexer
- Built-in Self-Test Mode
- Software-Controllable Sample and Hold
- Total Unadjusted Error . . . ±0.5 LSB Max
- Direct Replacement for Motorola MC145041
- On-Board System Clock
- End-of-Conversion (EOC) Output
- Pinout and Control Signals Compatible
 With the TLC1542/3 10-Bit A/D Converters
- CMOS Technology

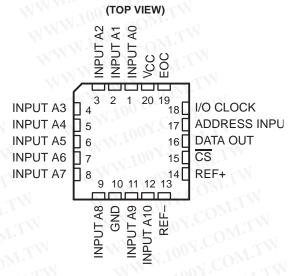
PARAMETER	VALUE		
Channel Acquisition/Sample Time	16 μs		
Conversion TIme (Max)	20 μs		
Samples per Second (Max)	25 × 10 ³		
Power Dissipation (Max)	10 mW		

description

The TLC542 is a CMOS converter built around an 8-bit switched-capacitor successive-approximation analog-to-digital converter. The device is designed for serial interface to a microprocessor or peripheral via a 3-state output with three inputs [including I/O CLOCK, \overline{CS} (chip select), and ADDRESS INPUT]. The TLC542 allows high-speed data transfers and sample rates of up to 40,000 samples per second. In addition to the high-speed converter and versatile control logic, an on-chip 12-channel



FN PACKAGE



analog multiplexer can sample any one of 11 inputs or an internal "self-test" voltage, and the sample and hold is started under microprocessor control. At the end of conversion, the end-of-conversion (EOC) output pin goes high to indicate that conversion is complete. Detailed information on interfacing to most popular microprocessors is readily available from the factory.

AVAILABLE OPTIONS

100 r. COM	PACKAGE				
N.100TA CON	CHIP CARRIER (FN)	PLASTIC DIP (N)	SMALL OUTLINE (DW)		
0°C to 70°C		TLC542CN	TLC542CDW		
-40°C to 85°C	TLC542IFN	TLC542IN	TLC542IDW		

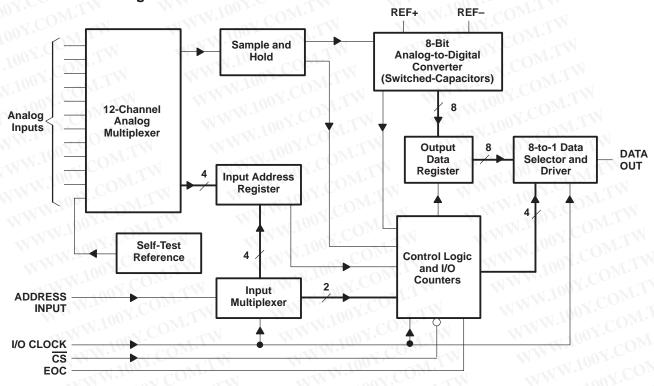


description (continued)

The converter incorporated in the TLC542 features differential high-impedance reference inputs that facilitate ratiometric conversion, scaling, and isolation of analog circuitry from logic and supply noises. A switched-capacitor design allows low-error (± 0.5 LSB) conversion in 20 μ s over the full operating temperature range.

The TLC542C is characterized for operation from 0° C to 70° C and the TLC542I is characterized for operation from -40° C to 85° C.

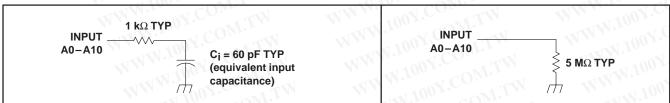
functional block diagram



typical equivalent inputs

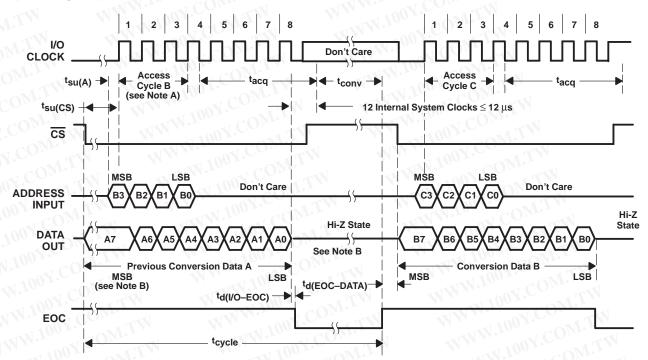
INPUT CIRCUIT IMPEDANCE DURING SAMPLING MODE

INPUT CIRCUIT IMPEDANCE DURING HOLD MODE





operating sequence



NOTES: A. To minimize errors caused by noise at the chip select input, the internal circuitry waits for two rising edges and one falling edge of the internal system clock after CS↓ before responding to control input signals. The CS setup time is given by the t_{Su(CS)} specifications. Therefore, no attempt should be made to clock-in an address until the minimum chip select setup time has elapsed.

B. The output is 3-stated on $\overline{\text{CS}}$ going high or on the negative edge of the eighth I/O clock.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	6.5 V
Input voltage range (any input)	
Output voltage range	
Peak input current range (any input)	
Peak total input current (all inputs)	±30 mA
Operating free-air temperature range: TLC542C	0°C to 70°C
TLC542l	–40°C to 85°C
Storage temperature range	–65°C to 150°C
Case temperature for 10 seconds: FN package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: DW or N package	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to digital ground with REF- and GND wired together (unless otherwise noted).



TLC542C, TLC542I 8-BIT ANALOG-TO-DIGITAL CONVERTERS WITH SERIAL CONTROL AND 11 INPUTS

SLAS075A - FEBRUARY 1989 - REVISED MARCH 1995

recommended operating conditions, $V_{CC} = 4.75$ to 5.5 V

TW WWW. 100Y	I THE WA	11007.	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}			4.75	5	5.5	V
Positive reference voltage, V _{ref+} (see Note 2)			V _{ref} _	Vcc	V _{CC} + 0.1	V
Negative reference voltage, V _{ref} (see Not	e 2)	W.100	-0.1	0	V _{ref+}	V
Differential reference voltage, V _{ref+} – V _{ref-}	(see Note 2)	M 4. 100x	1	Vcc	V _{CC} + 0.2	V
Analog input voltage (see Note 3)	ON COL	WW 100	0	VII	Vcc	V
High-level control input voltage, VIH	COM	WWW.	(C2)	Mr.	N	V
Low-level control input voltage, V _{IL}	1.100 x COW. 1	TANN TO	-7 C	DIVI	0.8	V
Setup time, address bits at data input befor	e I/O CLOCK↑, t _{Su(A)}	W Tax 1	400	Mo	1.41	ns
Hold time, address bits after I/O CLOCK↑,	h(A)	MM	000	- 1/	TW	ns
Hold time, CS low after 8th I/O CLOCK \(\hat{\chi}\), th(CS)			0	Co_{h}	W	ns
Setup time, $\overline{\text{CS}}$ low before clocking in first address bit, $t_{\text{SU}(\text{CS})}$ (see Note 4)			3.8	1 CO	VI.	μs
Input/output clock frequency, f _{clock(I/O)}			1100	1.1	Will	MHz
Input/output clock high, t _{WH(I/O)}			404	M.C.	WIIM	ns
Input/output clock low, t _{WL(I/O)}			404	MY.C	UT.	ns
I/O CLOCK transition time, t _f (see Note 3)	f _{clock(I/O)} ≤ 525 kHz	-31 -31	M.T.	~ ≤ 1 (100	
	f _{clock(I/O)} > 525 kHz	14	-TXN	100 .	40	ns
Operating free circumpurature T	TLC542C	TW	0	1007	70	°C
Operating free-air temperature, T _A	TLC542I	W.	-40	00	85	W

- NOTES: 2. Analog input voltages greater than that applied to REF+ convert as all ones (11111111), while input voltages less than that applied to REF- convert as all zeros (00000000). For proper operation, REF+ must be at least 1 V higher than REF-. Also, the total unadjusted error may increase as this differential reference voltage falls below 4.75 V.
 - 3. This is the time required for the clock input signal to fall from VIH min to VIL max or to rise from VIL max to VIH min. In the vicinity of normal room temperature, the devices function with input clock transition time as slow as 2 µs for remote data acquisition applications where the sensor and the A/D converter are placed several feet away from the controlling microprocessor.
 - 4. To minimize errors caused by noise at the chip select input, the internal circuitry waits for two rising edges and one falling edge of the internal system clock after $\overline{\text{CS}}$ ↓ before responding to control input signals. The $\overline{\text{CS}}$ setup time is given by the $t_{\text{SU}(CS)}$ specifications. Therefore, no attempt should be made to clock-in address data until the minimum chip select setup time has elapsed.

electrical characteristics over recommended operating temperature range, $V_{CC} = V_{ref+} = 4.75 \text{ V}$ to 5.5 V, $f_{clock(I/O)} = 1.1$ MHz (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN TYPT	MAX	UNIT	
Vон	High-level output v	oltage (DATA OUT)	V _{CC} = 4.75 V,	ΙΟΗ = -360 μΑ	2.4	N. 2	V
VOL	Low-level output vo	oltage	V _{CC} = 4.75 V,	I _{OL} = 1.6 mA	XX	0.4	V
	Off-state (high-impedance state) output current		$V_O = V_{CC}$	CS at V _{CC}	No.	10)0 x.
			$V_O = 0$,	CS at V _{CC}		-10	μА
lιΗ	High-level input current		VI = VCC	ON COM	0.005	2	μΑ
I _I L	Low-level input cur	rent 100	V _I = 0		-0.005	-2.5	μΑ
Icc	Operating supply c	urrent	CS at 0 V		1.2	2	mA
	Selected channel leakage current		Selected at V _{CC} , Unselected channel at 0 V	0°C to 70 °C	WI	0.4	
				– 40°C to 85°C	TW	-0.4	μΑ
I _{ref}	Maximum static an REF+	alog reference current into	V _{ref+} = V _{CC} ,	V _{ref} = GND	MITW	10	μА
0:	lanut sanasitassa	Analog inputs	W WY	AM. CA	7	55	
Ci	Input capacitance	Control inputs	OWIT		5	15	pF

[†] All typical values are at $T_A = 25$ °C.



operating characteristics over recommended operating free-air temperature range, $V_{CC} = V_{ref+} = 4.75$ to 5.5 V, $f_{clock(I/O)} = 1$ MHZ

-31	PARAMETER	TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
EL	Linearity error (see Note 5)	CO.	I. T		±0.5	LSB
EZS	Zero-scale error (see Note 6)	See Note 2	W.T.		±0.5	LSB
EFS	Full-scale error (see Note 6)	See Note 2	MIN		±0.5	LSB
OM.	Total unadjusted error (see Note 7)	WWW. OUN.C	VII.		±0.5	LSB
COMIT	Self-test output code	Input A11 address = 1011, See Note 8	01111101 (126)	128	10000011 (130)	
tconv	Conversion time	See operating sequence	17		20	μs
t _{cycle}	Total access and conversion cycle time	See operating sequence	A'COMP.	TW	40	μs
tacq	Channel acquisition time (sample cycle)	See operating sequence	COM		16	μs
t _V	Time ouput data remains valid after I/O CLK↓	See Figure 5	10	V_{J,A_J}		ns
td(IO-DATA)	Delay time, I/O CLK↓ to data output valid	See Figure 5	001.	TI	400	ns
td(IO-EOC)	Delay time, 8th I/O CLK↓ to EOC↓	See Figure 6	ON.CU	I.A.	500	ns
td(EOC-DATA)	Delay time, EOC↑ to data out (MSB)	See Figure 7	.100 ×1 C	$0_{M^{-1}}$	400	ns
tPZH, tPZL	Delay time, CS↓ to data out (MSB)	See Figure 2	1700	Mo	3.4	μs
tPHZ, tPLZ	Delay time, CS [↑] to data out (MSB)	See Figure 2	1100Y.		150	ns
tr(EOC)	Rise time	See Figure 7	W.	COR	100	ns
t _f (EOC)	Fall time	See Figure 6	11.100	J CO	100	ns
tr(bus)	Data bus rise time	See Figure 5	~1XI.100	· ·	300	ns
tf(bus)	Data bus fall time	See Figure 5	N 10	O.Y.	300	ns

† All typical values are at T_A = 25°C

NOTES: 2. Analog input voltages greater than that applied to REF+ convert to all ones (11111111), while input voltages less than that applied to REF- convert to all zeros (00000000). For proper operation, REF+ must be at least 1 V higher than REF-. Also, the total unadjusted error may increase as this differential reference voltage falls below 4.75 V.

- 5. Linearity error is the maximum deviation from the best straight line through the A/D transfer characteristics.
 - 6. Zero-scale Error is the difference between 00000000 and the converted output for zero input voltage; full-scale error is the difference between 11111111 and the converted output for full-scale input voltage.
 - 7. Total unadjusted error is the sum of linearity, zero-scale, and full-scale errors.
- 8. Both the input address and the output codes are expressed in positive logic. The A11 analog input signal is internally generated and is used for test purposes.



PARAMETER MEASUREMENT INFORMATION

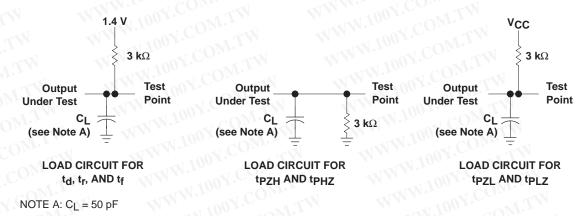


Figure 1. Load Circuits

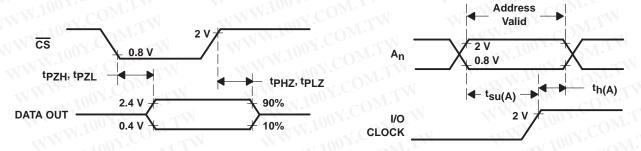


Figure 2. CS to Data Output Timing

Figure 3. Address Timing

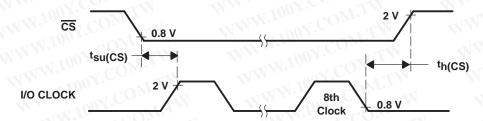


Figure 4. Figure 4. CS to I/O CLOCK Timing



PARAMETER MEASUREMENT INFORMATION

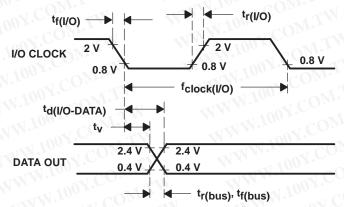


Figure 5. Data Output Timing

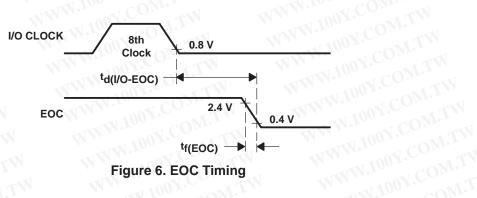
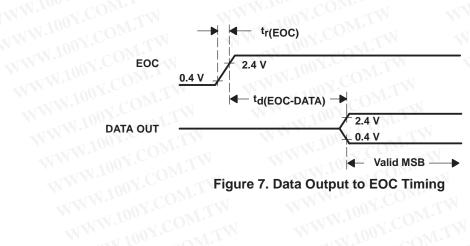


Figure 6. EOC Timing



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APPLICATION INFORMATION

simplified analog input analysis

Using the equivalent circuit in Figure 8, the time required to charge the analog input capacitance from 0 to V_S within 1/2 LSB can be derived as follows:

The capacitance charging voltage is given by

where

$$R_t = R_s + r_i$$

The final voltage to 1/2 LSB is given by

$$V_{\rm C}$$
 (1/2 LSB) = $V_{\rm S} - (V_{\rm S}/512)$ (2)

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(1)

Equating equation 1 to equation 2 and solving for time t_c gives

$$V_{S} - (V_{S}/512) = V_{S} \left(1 - e^{-t_{C}/R_{t}C_{i}}\right)$$
 (3)

and

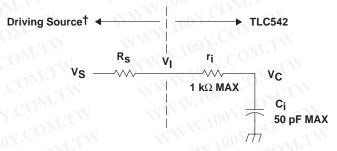
$$t_{c} (1/2 LSB) = R_{t} \times C_{i} \times ln(512)$$

$$\tag{4}$$

Therefore, with the values given the time for the analog input signal to settle is

$$t_{\rm C} (1/2 \text{ LSB}) = (R_{\rm S} + 1 \text{ k}\Omega) \times 60 \text{ pF} \times \ln(512)$$
 (5)

This time must be less than the converter sample time shown in the timing diagrams.



V_I = Input Voltage at INPUT A0-A10

V_S = External Driving Source Voltage

R_S = Source Resistance

ri = Input Resistance

C_i = Input Capacitance

† Driving source requirements:

- Noise and distortion for the source must be equivalent to the resolution of the converter.
- · R_S must be real at the input frequency.

Figure 8. Equivalent Input Circuit Including the Driving Source



PRINCIPLES OF OPERATION

The TLC542 is a complete data acquisition system on a single chip. The device includes such functions as analog multiplexer, sample and hold, 8-bit A/D converter, data and control registers, and control logic. Three control inputs (I/O CLOCK, $\overline{\text{CS}}$ (chip select), and ADDRESS INPUT) are included for flexibility and access speed. These control inputs and a TTL-compatible 3-state output are intended for serial communications with a microprocessor or microcomputer. With judicious interface timing, the TLC542 can complete a conversion in 20 μ s, while complete input-conversion-output cycles can be repeated every 40 μ s. Furthermore, this fast conversion can be executed on any of 11 inputs or its built-in self-test and in any order desired by the controlling processor.

When \overline{CS} is high, the DATA OUT terminal is in a 3-state condition, and the ADDRESS INPUT and I/O CLOCK terminals are disabled. When additional TLC542 devices are used, this feature allows each of these terminals, with the exception of the \overline{CS} terminal, to share a control logic point with their counterpart terminals on additional A/D devices. Thus, this feature minimizes the control logic terminals required when using multiple A/D devices.

The control sequence is designed to minimize the time and effort required to initiate conversion and obtain the conversion result. A normal control sequence is as follows:

- 1. $\overline{\text{CS}}$ is brought low. To minimize errors caused by noise at the $\overline{\text{CS}}$ input, the internal circuitry waits for two rising edges and then a falling edge of the internal system clock before recognizing the low $\overline{\text{CS}}$ transition. The MSB of the result of the previous conversion automatically appears on the DATA OUT terminal.
- 2. On the first four rising edges of the I/O CLOCK, a new positive-logic multiplexer address is shifted in, with the MSB of this address shifted first. The negative edges of these four I/O CLOCK pulses shift out the second, third, fourth, and fifth most significant bits of the result of the previous conversion. The on-chip sample and hold begins sampling the newly addressed analog input after the fourth falling edge of the I/O CLOCK. The sampling operation basically involves charging the internal capacitors to the level of the analog input voltage.
- 3. Three clock cycles are applied to the I/O CLOCK terminal and the sixth, seventh, and eighth conversion bits are shifted out on the negative edges of these clock cycles.
- 4. The final eighth clock cycle is applied to the I/O CLOCK terminal. The falling edge of this clock cycle initiates a 12-system clock (≈ 12 μs) additional sampling period while the output is in the high-impedance state. Conversion is then performed during the next 20 μs. After this final I/O CLOCK cycle, CS must go high or the I/O CLOCK must remain low for at least 20 μs to allow for the conversion function.

CS can be kept low during periods of multiple conversion. If CS is taken high, it must remain high until the end of conversion. Otherwise, a valid falling edge of CS causes a reset condition, which aborts the conversion process.

A new conversion may be started and the ongoing conversion simultaneously aborted by performing steps 1 through 4 before the 20-µs conversion time has elapsed. Such action yields the conversion result of the previous conversion and not the ongoing conversion.

The end-of-conversion (EOC) output goes low on the negative edge of the eighth I/O CLOCK. The subsequent low-to-high transition of EOC indicates the A/D conversion is complete and the conversion is ready for transfer.



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